SCAS001A - JUNE 1987 - REVISED APRIL 1993

- Flow-Through Architecture Optimizes PCB Layout
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- *EPIC*[™] (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

These devices contain a single 8-input NAND gate and perform the following Boolean functions in positive logic:

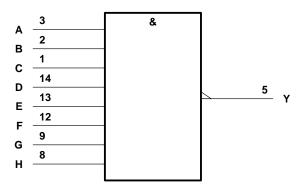
 $Y = \overline{A \bullet B \bullet C \bullet D \bullet E \bullet F \bullet G \bullet H} \text{ or}$ $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D} + \overline{E} + \overline{F} + \overline{G} + \overline{H}$

The 54AC11030 is characterized for operation over the full military temperature range of -55° C to 125°C. The 74AC11030 is characterized for operation from -40° C to 85°C.

FUNCTION TABLE

INPUTS A THRU H	OUTPUT Y
All inputs H	L
One or more inputs L	Н

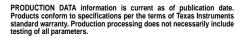
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

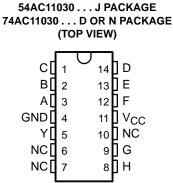
Pin numbers shown are for the D, J, and N packages.

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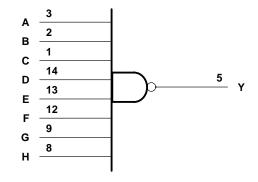


54AC11030 . . . FK PACKAGE (TOP VIEW)

	NCC NCC	
D] 4 ^{3 2 1 20 19} 18 [] G	
NC	5 17 N	С
D NC C NC] 4 2 7 20 1318 G] 5 17 [№] 6 16 H	
NC] 7 15 [N	С
В	8 14 N	С
	NC YC BND A	

NC – No internal connection

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	–0.5 V to 6 V
Input voltage range, VI (see Note 1)	–0.5 V to V _{CC} + 0.5 V
Output voltage range, V _O (see Note 1)	-0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions

			54	54AC11030		74	AC1103	0	UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage		3	5	5.5	3	5	5.5	V
		$V_{CC} = 3 V$	2.1			2.1			
VIH	High-level input voltage	$V_{CC} = 4.5 V$	3.15			3.15			V
		V _{CC} = 5.5 V	3.85			3.85			
		VCC = 3 V			0.9			0.9	
VIL	Low-level input voltage	V _{CC} = 4.5 V			1.35			1.35	V
		V _{CC} = 5.5 V			1.65			1.65	
VI	Input voltage		0		VCC	0		VCC	V
VO	Output voltage		0		VCC	0		VCC	V
		VCC = 3 V			-4			-4	
ЮН	High-level output current	V _{CC} = 4.5 V			-24			-24	mA
		V _{CC} = 5.5 V			-24			-24	
		V _{CC} = 3 V			12			12	
IOL	Low-level output current	V _{CC} = 4.5 V			24			24	mA
		V _{CC} = 5.5 V			24			24	
$\Delta t/\Delta v$	Input transition rise or fall rate	-	0		10	0		10	ns/V
Т _А	Operating free-air temperature		-55		125	-40		85	°C



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	TEST CONDITIONS		Т	4 = 25°C		54AC1	1030	74AC1	1030	
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		3 V	2.9			2.9		2.9		
	I _{OH} = - 50 μA	4.5 V	4.4			4.4		4.4		
		5.5 V	5.4			5.4		5.4		
Vali	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.4		2.48		V
Vон		4.5 V	3.94			3.7		3.8		v
	I _{OH} = – 24 mA	5.5 V	4.94			4.7		4.8		
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85				
	I _{OH} = -75 mA [†]	5.5 V						3.85		
		3 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	
		5.5 V			0.1		0.1		0.1	
Vei	I _{OL} = 12 mA	3 V			0.36		0.5		0.44	V
VOL		4.5 V			0.36		0.5		0.44	v
	I _{OL} = 24 mA	5.5 V			0.36		0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V					1.65			
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V							1.65	
lլ	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_{I} = V_{CC} \text{ or GND}, \qquad I_{O} = 0$	5.5 V			4		80		40	μA
Ci	$V_I = V_{CC}$ or GND	5 V		3.5						pF

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

ſ	PARAMETER	FROM	то	T,	₄ = 25°C	;	54AC1	1030	74AC1	1030	UNIT
	PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	^t PLH	Any	Y	1.5	6.9	9.1	1.5	10.6	1.5	9.9	20
	^t PHL			1.5	6.4	8.8	1.5	10.6	1.5	9.8	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER		FROM	FROM TO $T_A = 25^{\circ}C$		54AC11030		74AC11030		UNIT		
	PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	^t PLH	Any	Y	1.5	4.8	6.7	1.5	7.7	1.5	7.2	
	^t PHL			1.5	4.8	6.7	1.5	8	1.5	7.4	ns

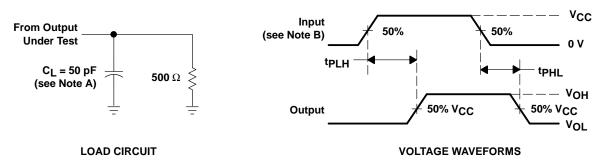
operating characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	TYP	UNIT
Cpd	Power dissipation capacitance per gate	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	42	pF



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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. $C_{\mbox{L}}$ includes probe and jig capacitance.
 - B. Input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r = 3 ns, t_f = 3 ns.
 - C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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